SY89833L

3.3V Ultra-Precision 1:4 LVDS Fanout Butter/Translator with Internal Termination

Features

- Guaranteed AC Performance Over-temperature and Voltage:
 - DC to > 2 GHz Throughput
 - <600 ps Propagation Delay (IN-to-Q)
 - <20 ps Within-device Skew
 - <150 ps Rise/Fall Times
- · Ultra-low Jitter Design:
 - 98 fs_{RMS} Phase Jitter
- Patented Any-in Input Termination and VT Pin Accepts DC- and AC-coupled Inputs
- · High-speed LVDS Outputs
- · 3.3V Power Supply Operation:
 - Industrial Temperature Range: -40°C to +85°C
- Available in 16-Lead 3 mm × 3 mm VQFN Package

Applications

- · Processor Clock Distribution
- · SONET Clock Distribution
- · Fibre Channel Clock Distribution
- · Gigabit Ethernet Clock Distribution

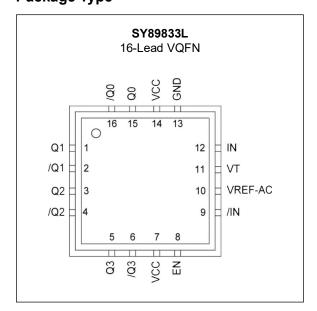
General Description

The SY89833L is a 3.3V, high-speed 2 GHz differential low voltage differential swing (LVDS) 1:4 fanout buffer optimized for ultra-low skew applications. Within device skew is guaranteed to be less than 20 ps over supply voltage and temperature.

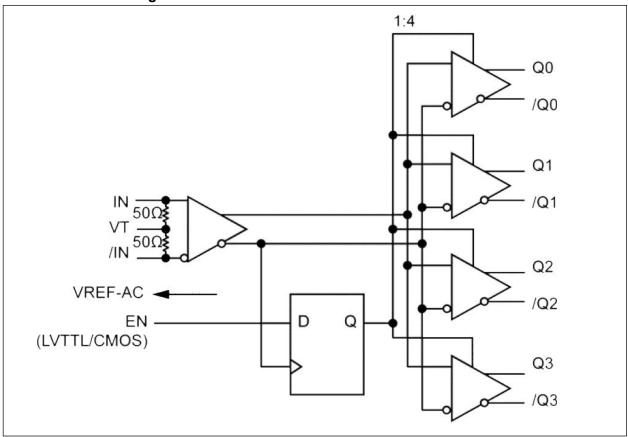
The differential input buffer has a unique internal termination design that allows access to the termination network through a VT pin. This feature allows the device to easily interface to different logic standards. A V_{REF-AC} reference is included for AC-coupled applications.

The SY89833L is part of Microchip's high-speed clock synchronization family. For 2.5V applications, the SY89832U provides similar functionality while operating from a 2.5V ±5% supply. For applications that require a different I/O combination, consult the Microchip website at www.microchip.com, and choose from a comprehensive product line of high-speed, low-skew fanout buffers, translators, and clock generators.

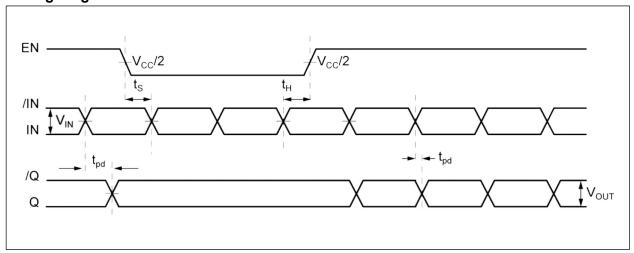
Package Type



Functional Block Diagram



Timing Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings[†]

Supply Voltage (V _{CC})	
Input Voltage (V _{IN})	0.5V to V _{CC} + 0.3V
LVDS Output Current (I _{OLIT})	
Input Current, Source or Sink Current on (VT)	

Operating Ratings^{††}

TABLE 1-1: ELECTRICAL CHARACTERISTICS

T _A = -40°C to +85°C unless otherwise noted. (Note 1)						
Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Power Supply	V _{CC}	3.0	3.3	3.6	V	_
Power Supply Current	I _{CC}	_	75	100	mA	No load, max. V _{CC}
Input Resistance (IN-to-VT)	R _{IN}	45	50	55	Ω	_
Differential Input Resistance (IN-to-/IN)	R _{DIFF-IN}	90	100	110	Ω	_
Input HIGH Voltage (IN-to-/IN)	V _{IH}	0.1	_	V _{CC} + 0.3	V	_
Input LOW Voltage (IN-to-/IN)	V _{IL}	-0.3	_	V _{IH} – 0.1	V	_
Input Voltage Swing (IN-to-/IN)	V _{IN}	0.1	_	V _{CC}	V	Note 2, see Figure 7-3
Differential Input Voltage Swing	V _{DIFF_IN}	0.2	_		V	Note 2, see Figure 7-4
Input Current (IN, /IN)	IIN	_	_	45	mA	Note 2
Reference Voltage	V _{REF-AC}	V _{CC} – 1.525	V _{CC} – 1.425	V _{CC} – 1.325	V	_

Note 1: The circuit is designed to meet the DC specifications shown in this table after thermal equilibrium has been established.

[†] **Notice:** Permanent device damage may occur if absolute maximum ratings are exceeded. This is a stress rating only and functional operation is not implied at conditions other than those detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

^{††} Notice: The data sheet limits are not guaranteed if the device is operated beyond the operating ratings.

^{2:} Due to the internal termination (see "Input Buffer Structure" section) the input current depends on the applied voltages at IN, /IN and VT inputs. Do not apply a combination of voltages that causes the input current to exceed the maximum limit.

TABLE 1-2: LVDS OUTPUTS DC ELECTRICAL CHARACTERISTICS

V_{CC} = 3.3V±10%, R_L = 100 Ω across the outputs; T_A = -40°C to +85°C. (Note 1)						
Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Output Voltage Swing	V _{OUT}	250	325	_	mV	See Figure 7-3
Differential Output Voltage Swing	V _{DIFF_OUT}	500	650	_	mV	See Figure 7-4
Output Common Mode Voltage	V _{OCM}	1.125	_	1.275	V	_
Change in Common Mode Voltage	ΔV _{OCM}	-50	_	50	mV	_

Note 1: The circuit is designed to meet the DC specifications shown in the above table after thermal equilibrium has been established.

TABLE 1-3: LVTTL/LVCMOS DC ELECTRICAL CHARACTERISTICS

$V_{CC} = 3.3V \pm 10\%$, $T_A = -40$ °C to +85°C. (Note 1)						
Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Input HIGH Voltage	V _{IH}	2.0	_	VCC	V	_
Input LOW Voltage	V _{IL}	0	_	0.8	V	_
Input HIGH Current	I _{IH}	-125	_	30	uA	_
Input LOW Current	I _{IL}	_	_	-300	uA	_

Note 1: The circuit is designed to meet the DC specifications shown in the above table after thermal equilibrium has been established.

TABLE 1-4: AC ELECTRICAL CHARACTERISTICS

V_{CC} = 2.5V ±5% or 3.3V ±10%; R_L = 50 Ω to V_{CC} – 2V; T_A = –40°C to + 85°C, unless otherwise noted. (Note 1)						
Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Maximum Frequency	f _{MAX}	2.0	_	_	GHz	V _{OUT} ≥ 200 mV
Propagation Delay	+	400	500	600	ne	VIN < 400mV
IN-to-Q	t _{pd}	330	440	530	ps	VIN ≥ 400mV
Within-Device Skew	t _{SKEW}		4	20	ps	Note 2
Part-to-Part Skew	t _{SKEW}	_	_	200	ps	Note 3
Set-up Time EN-to-IN, /IN	t _S	300	_	_	ps	Note 4
Hold Time EN-to-IN, /IN	t _H	500	_	_	ps	Note 4
RMS Phase Jitter	t _{JITTER}	_	98	_	fs	Output = 622 MHz, Integration Range: 12 kHz – 20 MHz
Output Rise/Fall Times (20% to 80%)	t _r , t _f	60	110	190	ps	At full output swing

- Note 1: High-frequency AC parameters are guaranteed by design and characterization.
 - 2: Within device skew is measured between two different outputs under identical input transitions.
 - **3:** Part-to-part skew is defined for two parts with identical power supply voltages at the same temperature and no skew at the edges at the respective inputs.
 - **4:** Set-up and hold times apply to synchronous applications that intend to enable/disable before the next clock cycle. For asynchronous applications, set-up and hold times do not apply.

TABLE 1-5: TEMPERATURE SPECIFICATIONS

Note 1						
Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Temperature Range					1	
Operating Temperature Range	T _A	-40	_	+85	°C	_
Maximum Operating Junction Temperature		_	_	+125	°C	_
Lead Temperature	T _{LEAD}	_	260	_	°C	Soldering, 20 sec.
Storage Temperature Range	T _S	-65	_	+150	°C	_
Package Thermal Resistance (Note 1)						
VQFN, Still Air	θ_{JA}	_	60	_	°C/W	_
VQFN	Ψ_{JB}	_	33	_	°C/W	_

Note 1: Package thermal resistance assumes the exposed pad is soldered (or equivalent) to the device's most negative potential on the PCB. The Ψ_{JB} and θ_{JA} values are determined for a 4-layer board at the still-air package thermal resistance, unless otherwise stated.

2.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 2-1.

TABLE 2-1: PIN FUNCTION TABLE

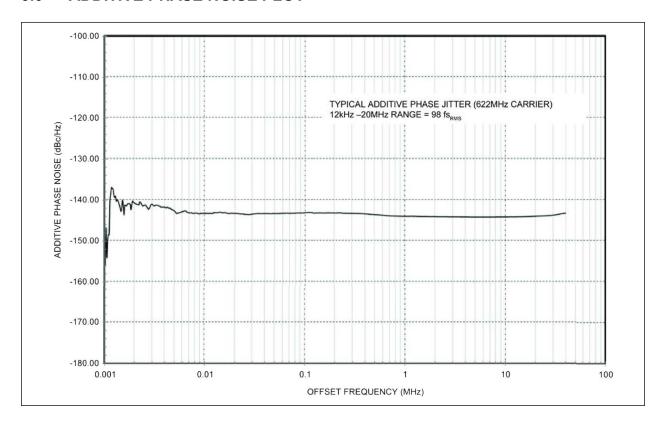
Pin Number	Pin Name	Description					
15, 16	Q0, /Q0						
1, 2	Q1, /Q1	LVDS Differential Outputs: Normally terminated with 100Ω across the pair (Q, /Q).					
3, 4	Q2, /Q2	See Section 7.0, LVDS Outputs. Unused outputs should be terminated with a resistor across each pair.					
5, 6	Q3, /Q3						
8	EN	This single-ended TTL/CMOS-compatible input functions as a synchronous output enable. The synchronous enable ensures that enable/disable will only occur when the outputs are in a logic LOW state. Note that this input is internally connected to a $25 \mathrm{k}\Omega$ pull-up resistor and will default to logic HIGH state (enabled) if left open.					
9, 12	/IN, IN	Differential Inputs: These input pairs are the differential signal inputs to the device. Inputs accept AC- or DC-Coupled differential signals as small as 100mV. Each pin of a pair internally terminates to a VT pin through 50Ω . Note that these inputs will default to an intermediate state if left open. Please refer to Section 8.0, Input Interface Applications for more details.					
10	VREF-AC	Reference Voltage: These outputs bias to VCC-1.4V.They are used when AC coupling the inputs (IN, /IN). For AC-Coupled applications, connect VREF-AC to VT pin and bypass with 0.01µF low ESR capacitor to VCC. See Section 8.0, Input Interface Applications for more details. Maximum sink/source current is ±1.5mA. Due to the limited drive capability, each VREF-AC pin is only intended to drive its respective VT pin.					
11	VT	Input Termination Center-Tap: Each side of the differential input pair terminates to a VT pin. The VT pins provide a center-tap to a termination network for maximum interface flexibility. See Section 8.0, Input Interface Applications for more details.					
13	GND	Ground. GND pins and exposed pad must be connected to the most negative potential of the device ground.					
7, 14	VCC	Positive Power Supply: Bypass with $0.1\mu F//0.01\mu F$ low ESR capacitors and place as close to each VCC pin as possible.					

TABLE 2-2: TRUTH TABLE

IN	/IN	EN	Q	/Q
0	1	1	0	1
1	0	1	1	0
X	X	0	0 (Note 1)	1 (Note 1)

Note 1: On the next negative transition of the input signal (IN).

3.0 ADDITIVE PHASE NOISE PLOT



4.0 TYPICAL CHARACTERISTICS

 V_{CC} = 3.3V, GND = 0V, V_{IN} = 400 mV, R_{L} = 100 Ω across the outputs; T_{A} = 25°C, unless otherwise stated.

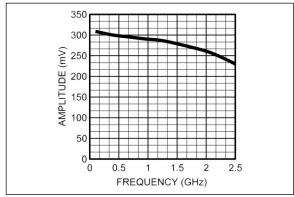


FIGURE 4-1: OUTPUT SWING VS. FREQUENCY.

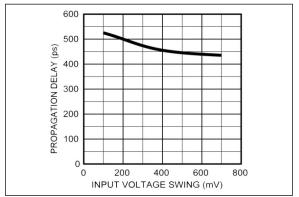


FIGURE 4-2: PROPAGATION DELAY VS. INPUT VOLTAGE SWING.

5.0 **FUNCTIONAL CHARACTERISTICS**

Typical output waveforms. V_{CC} = 3.3V; GND = 0V; V_{IN} = 800 mV; R_L = 50 Ω to V_{CC} – 2V; T_A = 25°C, unless otherwise noted.

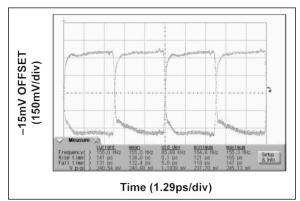


FIGURE 5-1: 155 MHZ OUTPUT.

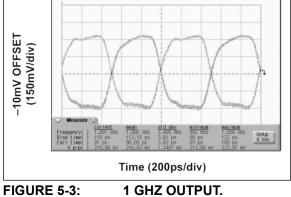


FIGURE 5-3:

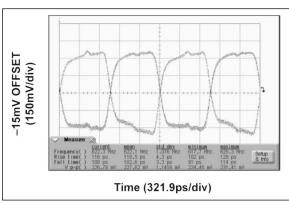


FIGURE 5-2: **622 MHZ OUTPUT.**

6.0 INPUT STAGE

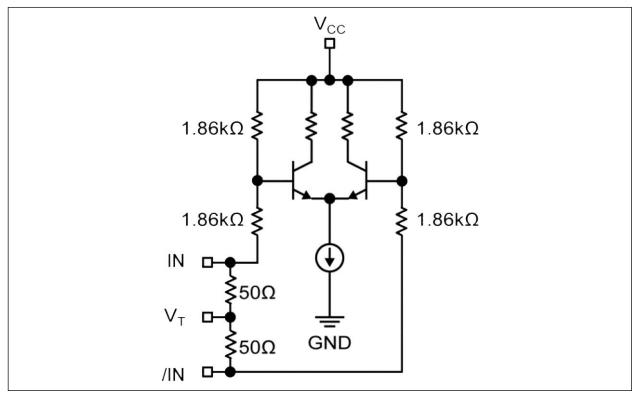


FIGURE 6-1: SIMPLIFIED DIFFERENTIAL INPUT BUFFER.

7.0 LVDS OUTPUTS

LVDS specifies a small swing of 325 mV typical, on a nominal 1.20V common mode above ground. The common-mode voltage has tight limits to permit large variations in ground noise between a LVDS driver and receiver.

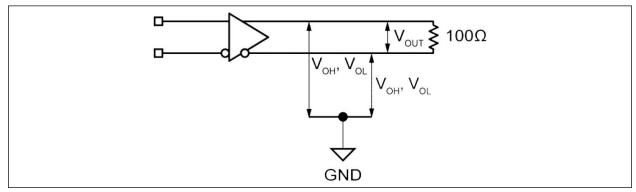


FIGURE 7-1: LVDS DIFFERENTIAL MEASUREMENT.

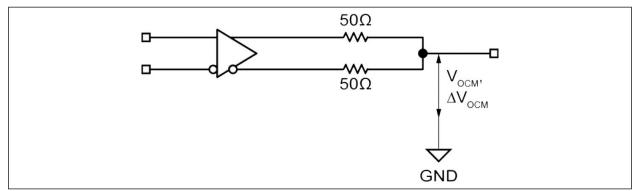


FIGURE 7-2: LVDS COMMON MODE MEASUREMENT.

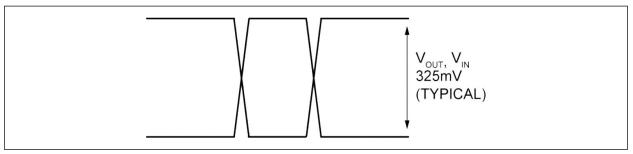


FIGURE 7-3: SINGLE-ENDED SWING.

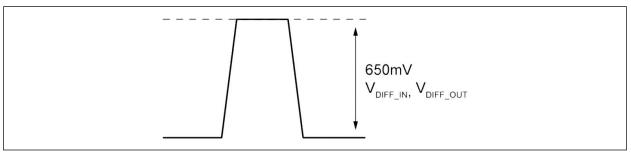


FIGURE 7-4: DIFFERENTIAL SWING.

8.0 INPUT INTERFACE APPLICATIONS

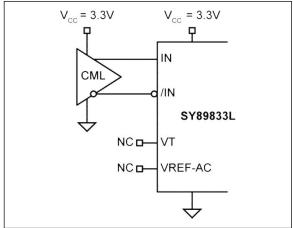


FIGURE 8-1: DC-COUPLED CML INPUT INTERFACE.

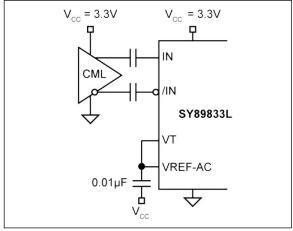


FIGURE 8-2: AC-COUPLED CML INPUT INTERFACE.

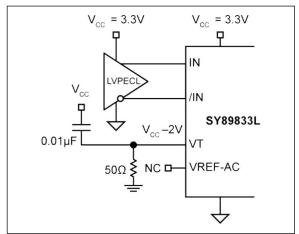


FIGURE 8-3: DC-COUPLED LVPECL INPUT INTERFACE.

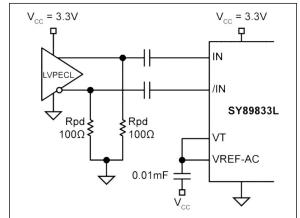


FIGURE 8-4: AC-COUPLED LVPECL INPUT INTERFACE.

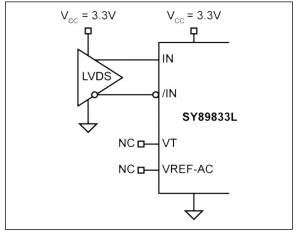


FIGURE 8-5: DC-COUPLED LVDS INPUT INTERFACE.

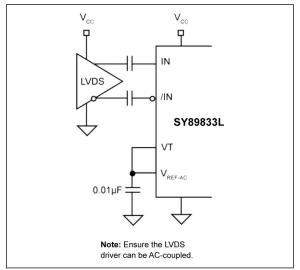
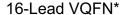
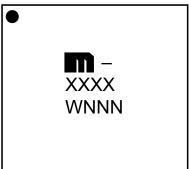


FIGURE 8-6: AC-COUPLED LVDS INPUT INTERFACE.

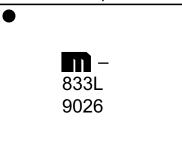
9.0 PACKAGING INFORMATION

9.1 Package Marking Information





Example*



Legend: XX...X Product code or customer-specific information

W Week code

NNN Alphanumeric traceability code (week)

* This package is Pb-free. The Pb-free JEDEC designator can be found on the outer packaging for this package.

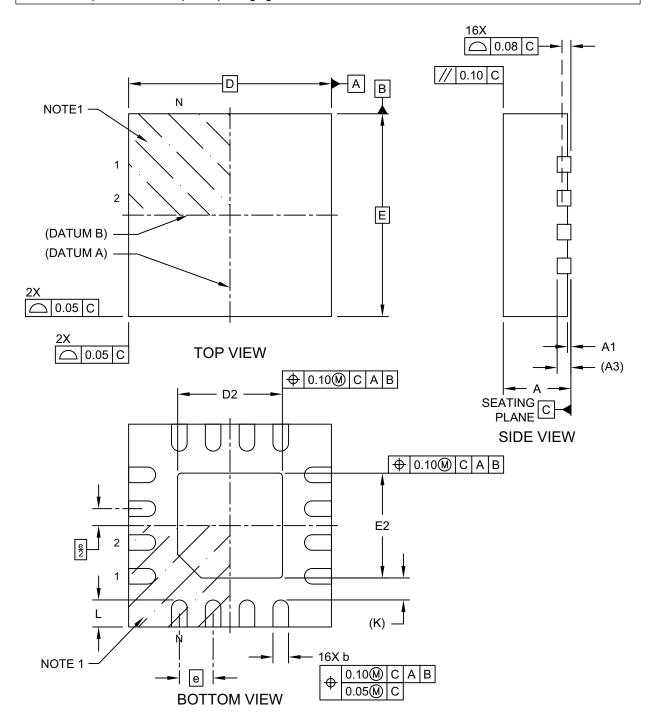
• Pin one index is identified by a dot

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or may not include the corporate logo.

Underbar (_) and/or Overbar (_) symbol may not be to scale.

16-Lead 3 mm × 3 mm VQFN [NCA] Package Outline and Recommended Land Pattern

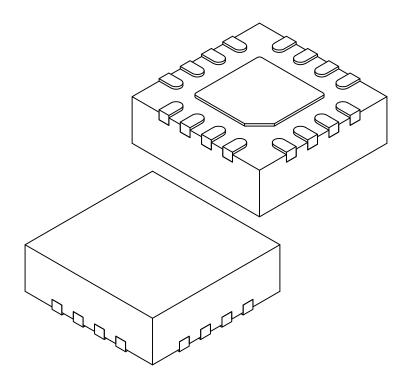
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-1103-NCA Rev C Sheet 1 of 2

16-Lead 3 mm × 3 mm VQFN [NCA] Package Outline and Recommended Land Pattern

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units			S
Dimension	Limits	MIN	NOM	MAX
Number of Terminals	N		16	
Pitch	е		0.50 BSC	
Overall Height	Α	0.80	0.90	1.00
Standoff	A1	0.00	0.02	0.05
Terminal Thickness	A3	0.203 REF		
Overall Length	D		3.00 BSC	
Exposed Pad Length	D2	1.50	1.55	1.60
Overall Width	Е		3.00 BSC	
Exposed Pad Width	E2	1.50	1.55	1.60
Terminal Width	b	0.18	0.23	0.28
Terminal Length	L	0.35	0.40	0.45
Terminal-to-Exposed-Pad	K		0.33 REF	

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

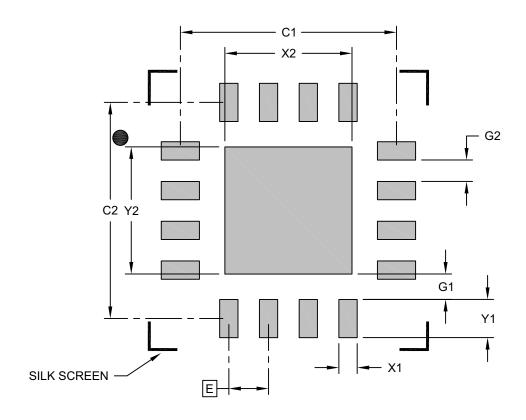
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1103-NCA Rev C Sheet 2 of 2

16-Lead 3 mm × 3 mm VQFN [NCA] Package Outline and Recommended Land Pattern

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	N	/ILLIMETER	S	
Dimension	Limits	MIN	NOM	MAX
Contact Pitch	Е		0.50 BSC	
Center Pad Width	X2			1.60
Center Pad Length	Y2			1.60
Contact Pad Spacing	C1		2.72	
Contact Pad Spacing	C2		2.72	
Contact Pad Width (Xnn)	X1			0.23
Contact Pad Length (Xnn)	Y1			0.48
Contact Pad to Center Pad (Xnn)	G1	0.32		
Contact Pad to Contact Pad (Xnn)	G2	0.27		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-3103-NCA Rev C

APPENDIX A: REVISION HISTORY

Revision A (May 2025)

- Converted Micrel data sheet for SY89833L to Microchip format as DS20006846A.
- Minor text changes throughout.

SY89833L

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

PART NO.	X	<u>x</u>	_ X
Device	Supply P Voltage Range	acka	nge Temperature Special Range Processing
Device:	SY89833	=	Ultra-Precision 1:4 LVPECL Fanout Buffer/Translator with Internal Termination Precision Edge [®]
Voltage Option:	L	=	3.3V
Package:	М	=	16-Lead VQFN
Temperature Range:	G	=	–40°C to 85°C
Special Processing:	<blank> -TR</blank>	=	100/Tube 1,000/Tape & Reel

Examples:

- a) **SY89833LMG**
 - 3.3V, 16-Lead VQFN, -40°C to 85°C, 100/Tube
- b) SY89831LMG-TR
 - 3.3V, 16-Lead VQFN, -40°C to 85°C, 1,000/Tape & Reel

SY89833L

NOTES:

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